

RJH60D7BDPQ-E0

600V - 50A - IGBT Application: Inverter

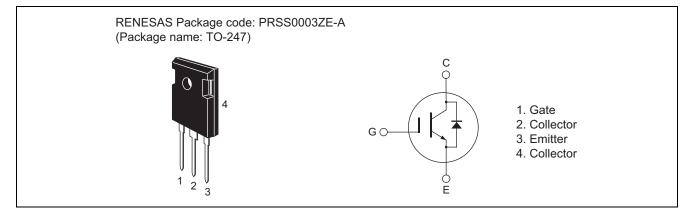
R07DS0795EJ0300 Rev.3.00 Jul 20, 2016

Features

- Short circuit withstand time (5 µs typ.)
- Low collector to emitter saturation voltage $V_{CE(sat)} = 1.6 V$ typ. (at $I_C = 50 A$, $V_{GE} = 15 V$, $Ta = 25^{\circ}C$)
- Built in fast recovery diode (25 ns typ.) in one package
- Trench gate and thin wafer technology
- High speed switching

 $t_f = 50$ ns typ. (at $V_{CC} = 300$ V, $V_{GE} = 15$ V, $I_C = 50$ A, Rg = 5 Ω , $Ta = 25^{\circ}C$, inductive load)

Outline



Absolute Maximum Ratings

				$(Ta = 25^{\circ}C)$
Item		Symbol	Ratings	Unit
Collector to emitter voltage / diode reverse voltage		V _{CES} / V _R	600	V
Gate to emitter voltage		V _{GES}	±30	V
Collector current	Tc = 25°C	Ι _C	90	А
	Tc = 100°C	lc	50	А
Collector peak current		ic(peak) Note1	200	А
Collector to emitter diode forward current		İDF	30	А
Collector to emitter diode forward peak current		i _{DF} (peak) Note1	120	А
Collector dissipation		Pc Note2	Pc ^{Note2} 300	
Junction to case thermal resistance (IGBT)		θj-c ^{Note2}	0.42	°C/W
Junction to case thermal resistance (Diode)		θj-cd Note2	1.1	°C/W
Junction temperature		Tj	150	°C
Storage temperature		Tstg	-55 to +150	°C

Notes: 1. $PW \le 10 \ \mu s$, duty cycle $\le 1\%$

2. Value at Tc = 25°C



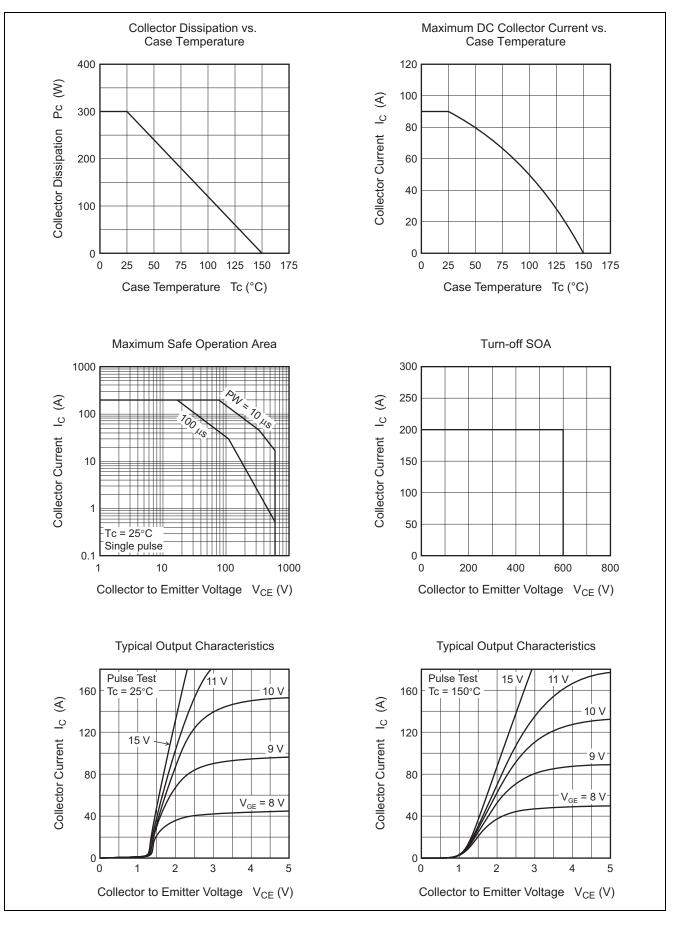
Electrical Characteristics

Item	Symbol	Min	Тур	Max	Unit	Test Conditions	
Collector to emitter breakdown voltage	$V_{\text{BR}(\text{CES})}$	600	—	—	V	$I_{C} = 10 \ \mu A, \ V_{GE} = 0$	
Zero gate voltage collector current / Diode reverse current	Ices / Ir	_	—	5	μΑ	$V_{CE} = 600 \text{ V}, \text{ V}_{GE} = 0$	
Gate to emitter leak current	IGES	_	—	±1	μΑ	$V_{GE} = \pm 30 \text{ V}, \text{ V}_{CE} = 0$	
Gate to emitter cutoff voltage	V _{GE(off)}	4.0	—	6.0	V	V _{CE} = 10 V, I _C = 1 mA	
Collector to emitter saturation voltage	V _{CE(sat)}	_	1.6	2.2	V	$I_{C} = 50 \text{ A}, V_{GE} = 15 \text{ V}^{\text{Note3}}$	
	V _{CE(sat)}	_	1.8	_	V	$I_{C} = 90 \text{ A}, V_{GE} = 15 \text{ V}^{\text{Note3}}$	
Input capacitance	Cies		3150	_	pF	V _{CE} = 25 V	
Output capacitance	Coes	_	180		pF	V _{GE} = 0 f = 1 MHz	
Reveres transfer capacitance	Cres		95	_	pF		
Total gate charge	Qg	_	125	—	nC	V _{GE} = 15 V	
Gate to emitter charge	Qge	_	25	—	nC	V _{CE} = 300 V	
Gate to collector charge	Qgc	_	50	—	nC	Ic = 50 A	
Turn-on delay time	t _{d(on)}	_	60	—	ns	Vcc = 300 V	
Rise time	tr	_	50	—	ns	V _{GE} = 15 V	
Turn-off delay time	t _{d(off)}	_	180	—	ns	Ic = 50 A Rg = 5 Ω	
Fall time	tr	_	50	—	ns		
Turn-on energy	Eon	_	0.7	—	mJ	 (Inductive load) 	
Turn-off energy	Eoff	_	1.4	—	mJ		
Total switching energy	Etotal		2.0	—	mJ		
Short circuit withstand time	t _{sc}	3.0	5.0		μS	$V_{CC} \leq 360$ V, V_{GE} = 15 V	
FRD forward voltage	VF		2.5	3.0	V	I _F = 30 A ^{Note3}	
FRD reverse recovery time	trr	_	25	—	ns	IF = 30 A	
FRD reverse recovery charge	Qrr	_	32	—	μC	di⊧/dt = 100 A/µs	
FRD peak reverse recovery current	Irr		1.5		Α		

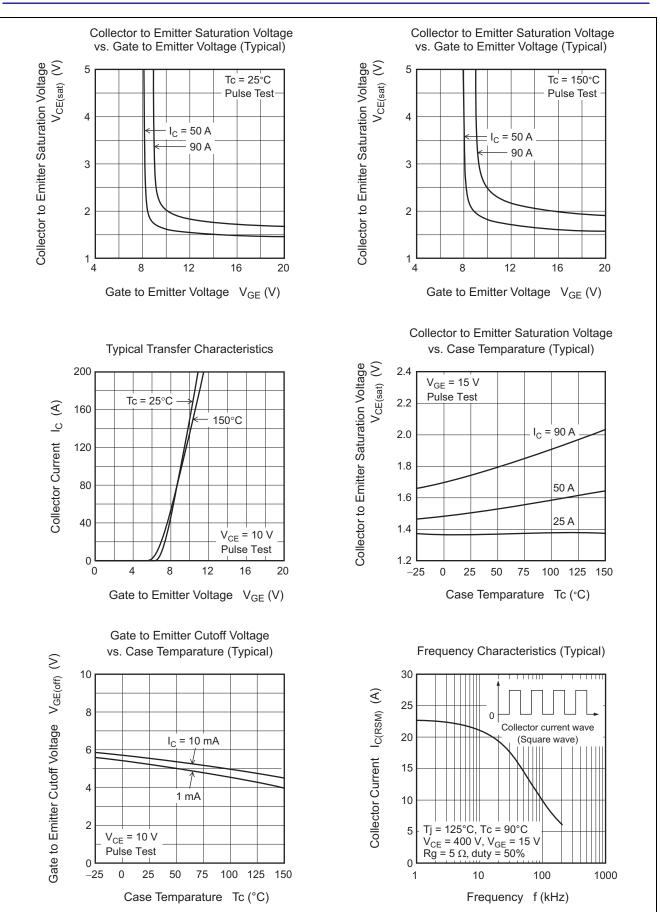
Notes: 3. Pulse test

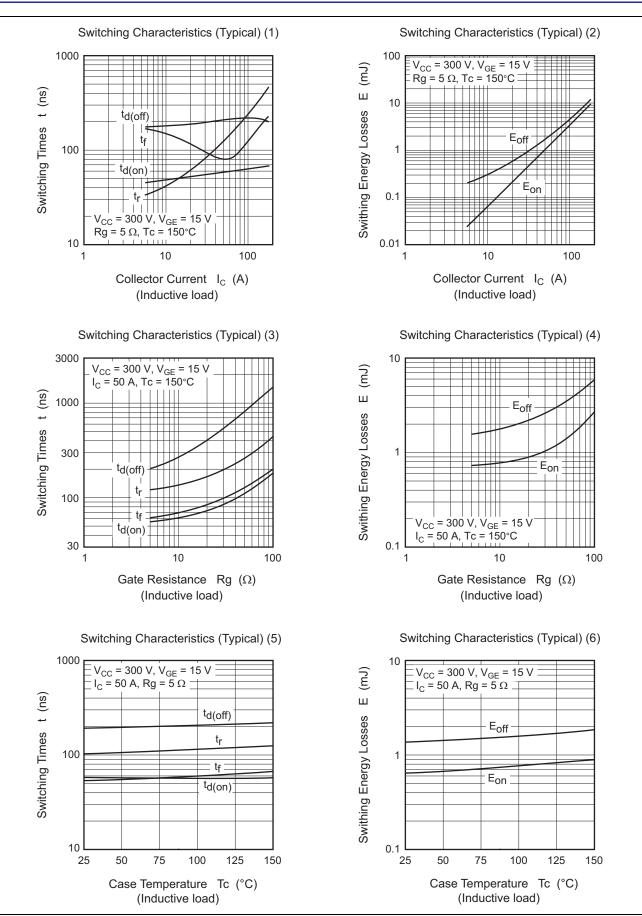


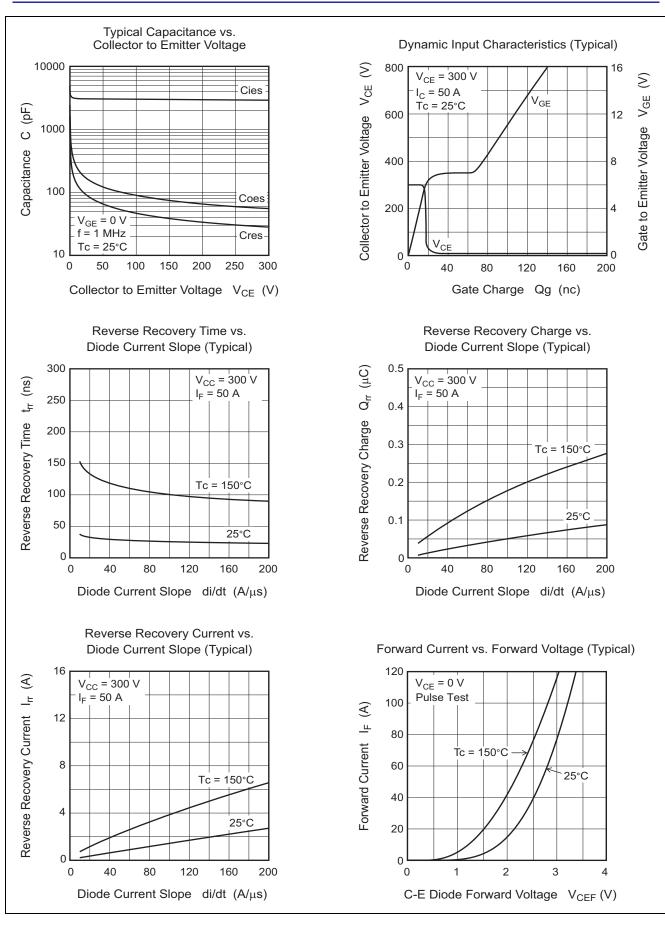
Main Characteristics



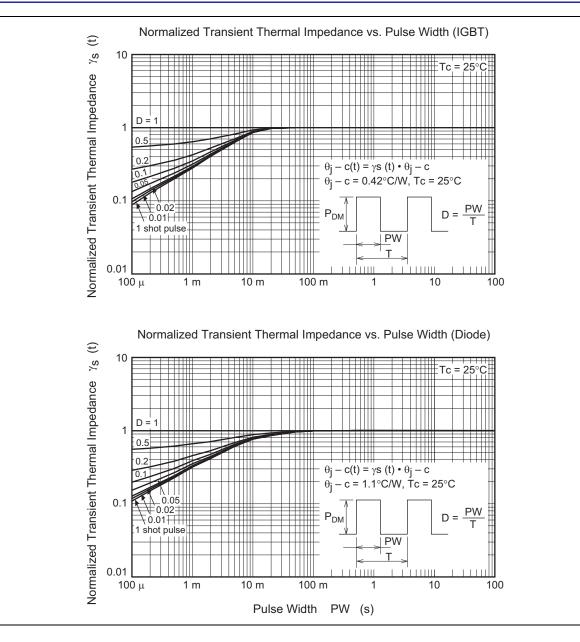




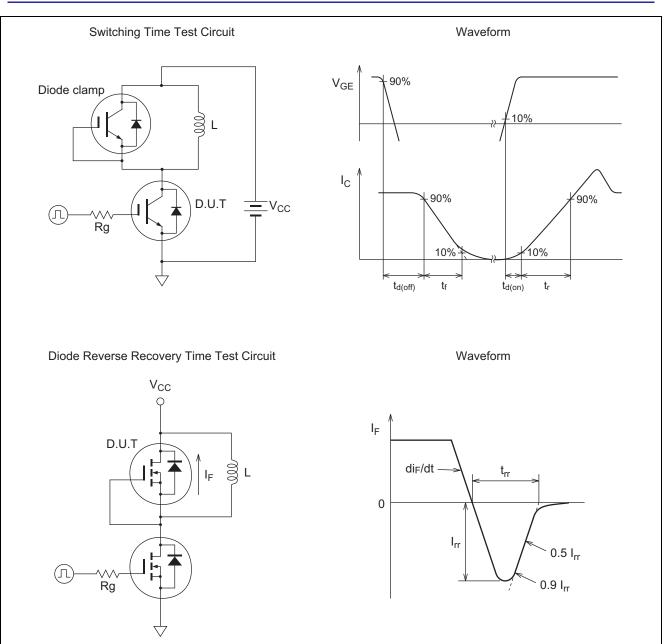






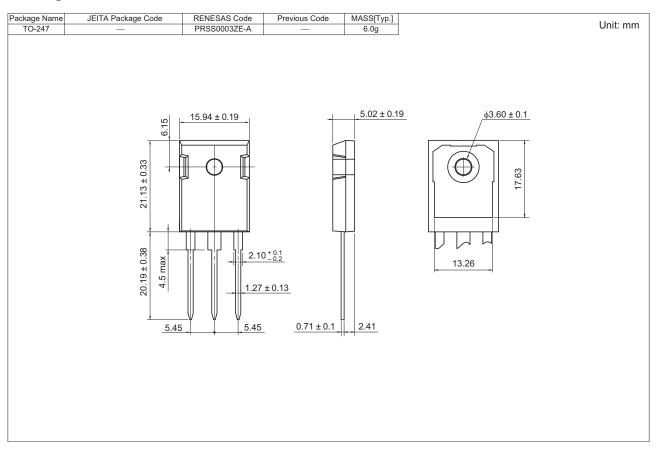








Package Dimension



Ordering Information

Orderable Part No.	Quantity	Shipping Container
RJH60D7BDPQ-E0#T2	240 pcs	Box (Tube)



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